

# SOT223 PNP SILICON PLANAR MEDIUM POWER DARLINGTON TRANSISTOR

## FZT705

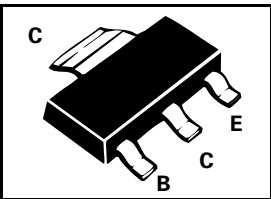
ISSUE 2 - OCTOBER 1995

### FEATURES

- \* 2A CONTINUOUS CURRENT
- \* FAST SWITCHING
- \* GUARANTEED HFE SPECIFIED UP TO 2A

COMPLEMENTARY TYPE – FZT 605

PART MARKING DETAIL – FZT705



### ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	VALUE	UNIT
Collector-Base Voltage	$V_{CBO}$	-140	V
Collector-Emitter Voltage	$V_{CEO}$	-120	V
Emitter-Base Voltage	$V_{EBO}$	-10	V
Peak Pulse Current	$I_{CM}$	-4	A
Continuous Collector Current	$I_C$	-2	A
Power Dissipation	$P_{TOT}$	2	W
Operating and Storage Temperature Range	tj:tstg	-55 to +150	°C

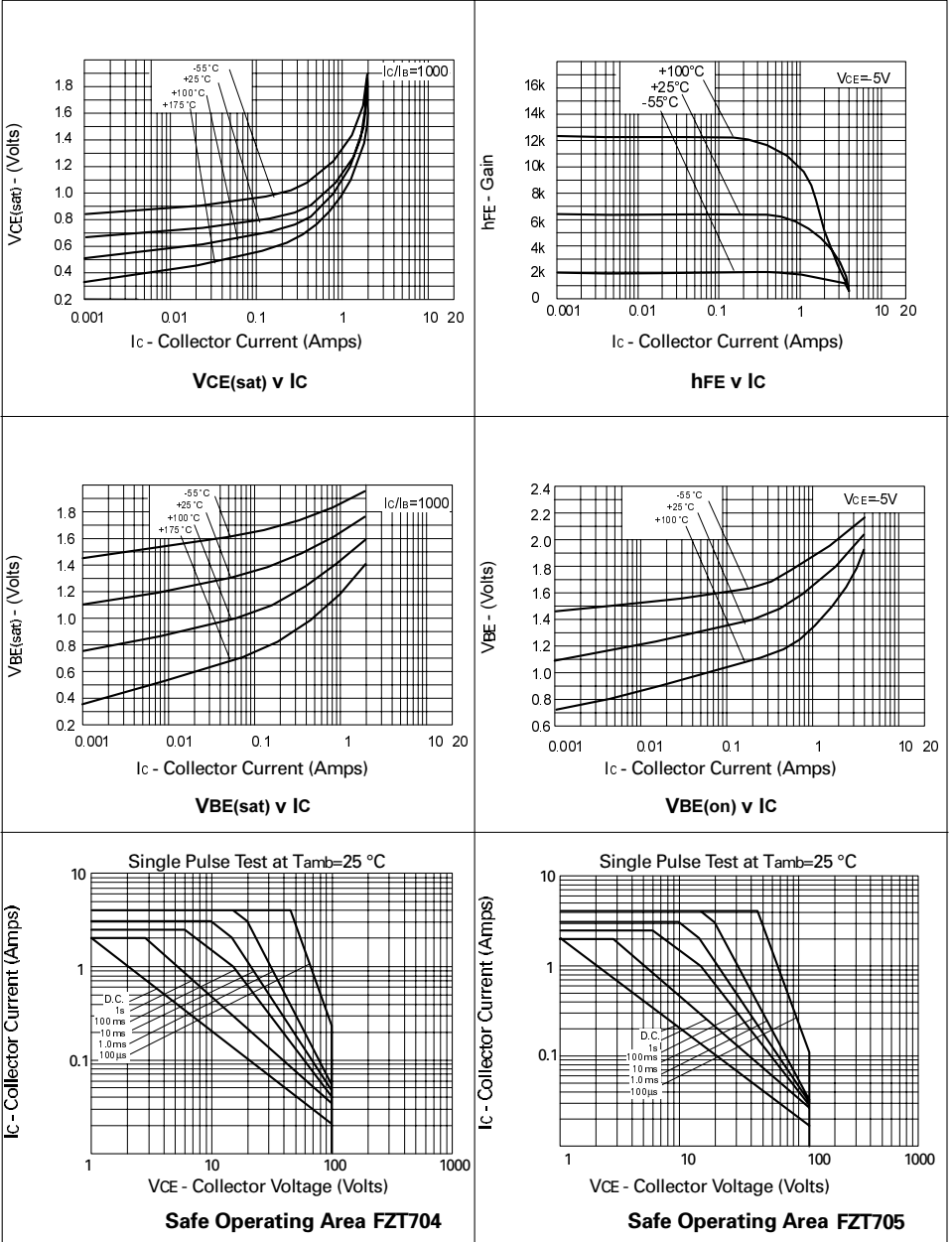
### ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^\circ\text{C}$ unless otherwise stated).

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS.
Breakdown Voltages	$V_{(BR)CBO}$	-140			V	$I_C = -100\text{mA}$
	$V_{(BR)CEO}$	-120			V	$I_C = -10\text{mA}^*$
	$V_{(BR)EBO}$	-10			V	$I_E = -100\mu\text{A}$
Collector Cut-Off Current	$I_{CBO}$			-0.1 -10	$\mu\text{A}$	$V_{CB} = -120\text{V}$ $V_{CB} = -120\text{V}, T_{amb} = 100^\circ\text{C}$
	$I_{CES}$			-10	$\mu\text{A}$	$V_{CES} = -80\text{V}$
Emitter Cut-Off Current	$I_{EBO}$			-0.1	$\mu\text{A}$	$V_{EB} = -8\text{V}$
Saturation Voltages	$V_{CE(sat)}$			-1.3 -2.5	V	$I_C = -1\text{A}, I_B = -1\text{mA}$ $I_C = -2\text{A}, I_B = -2\text{mA}$
	$V_{BE(sat)}$			-1.8	V	$I_C = -1\text{A}, I_B = -10\text{mA}$
Base-Emitter Turn-On Voltage	$V_{BE(on)}$			-1.7	V	$I_C = -1\text{A}, V_{CE} = -5\text{V}$
Static Forward Current Transfer	$h_{FE}$	3000 3000 3000 2000		30000		$I_C = -10\text{mA}, V_{CE} = -5\text{V}$ $I_C = -100\text{mA}, V_{CE} = -5\text{V}$ $I_C = -1\text{A}, V_{CE} = -5\text{V}$ $I_C = -2\text{A}, V_{CE} = -5\text{V}$
Transitional Frequency	$f_T$		160		MHz	$I_C = -100\text{mA}, V_{CE} = -10\text{V}$ $f = 20\text{MHz}$
Output Capacitance	$C_{obo}$		15		pF	$V_{EB} = -10\text{V}, f = 1\text{MHz}$
Switching Times	$T_{on}$		0.6		$\mu\text{s}$	$I_C = -0.5\text{A}, V_{CE} = -10\text{V}$
	$T_{off}$		0.8		$\mu\text{s}$	$I_{B1} = I_{B2} = 0.5\text{mA}$

\*Measured under pulsed conditions. Pulse width=300 $\mu\text{s}$ . Duty cycle  $\leq 2\%$   
Spice parameter data is available upon request for this device

# FZT705 FZT704

## TYPICAL CHARACTERISTICS





LittleDiode supplies new, hard to find or obsolete electronic components and semiconductors all over the world.

With over two million different components listed you are sure to find the part you need.

Feel free to visit us today at our online store:

[LittleDiode.com](http://LittleDiode.com)

Looking forward to providing you with the best possible service.